

GaAs Transfer Switch, DC-3.0 GHz

Rev. V5

Features

- Small Ceramic Package, 0.250" Sq.
- · Fast Switching Speed, 4 ns Typical
- Ultra Low DC Power Consumption
- 50 Ohm Nominal Impedance
- MIL-STD-883 screening available
- Lead-Free CR-4 Package
- 260°C Reflow Compatible
- RoHS* Compliant

Description

M/A-COM's SW-283-PIN is a GaAs MMIC transfer switch packaged in lead-free, surface mount CR-4 ceramic style packages. SW-283-PIN offers low insertion loss, high isolation, and fast switching. This ceramic switch platform has a common footprint for all three designs. The CR-4 package is hermetically sealed, making this switch ideal for space, military radios, and other environmentally harsh applications.

Typical applications include synthesizer switching, transmit/receive switching, switch matrices and filter banks in systems such as radio and cellular equipment, PCM, GPS, and fiber optic modules.

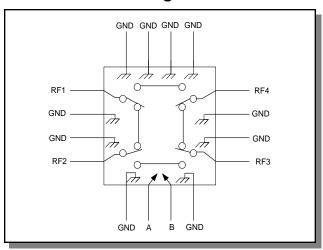
The SW-283-PIN transfer switch contains a monolithic GaAs MMIC which is fabricated using a 1.0 micron MESFET process.

Ordering Information

| Part Number | Package | |
|-------------|----------------|--|
| SW-283-PIN | Bulk Packaging | |

Note: Reference Application Note M513 for reel size information.

Functional Block Diagram



Pin Configuration

| Pin No. | Function | Pin No. | Function |
|---------|----------|---------|----------|
| 1 | RF1 | 9 | RF3 |
| 2 | GND | 10 | GND |
| 3 | GND | 11 | GND |
| 4 | RF2 | 12 | RF4 |
| 5 | GND | 13 | GND |
| 6 | А | 14 | GND |
| 7 | В | 15 | GND |
| 8 | GND | 16 | GND |

The metal bottom of the case must be connected to RF and DC ground.

^{*} Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

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Visit www.macomtech.com for additional data sheets and product information.

SW-283-PIN



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Electrical Specifications: $T_A = 25$ °C, $Z_0 = 50\Omega^{1,2}$

| Parameter | Test Conditions | Frequency | Units | Min | Тур | Max |
|---|---|--|--------------------------|----------------------|--------------------------|-----------------------------------|
| Insertion Loss | _ | DC - 3 GHz DC - 2 GHz DC - 1 GHz DC - 0.5 GHz | dB dB dB dB | _ _ _ _ | _ _ _ _ | 2.1 1.8 1.3 1.0 |
| VSWR | SWR DC - 3 GHz Ratio DC - 2 GHz Ratio DC - 1 GHz Ratio DC - 0.5 GHz Ratio | | Ratio Ratio | _ _ _ _ | _ _ _ _ | 1.9:1 1.7:1 1.3:1 1.25:1 |
| Isolation | _ | DC - 3 GHz DC - 2 GHz DC - 1 GHz DC - 0.5 GHz | dB dB dB dB | 20 25 40 45 | _ _ _ _ | _ _ _ |
| Trise, Tfall Ton, Toff Transients | 10/90% or 90/10% RF 50% CTL to 90/10% RF In-Band | _ _ _ | nS nS mV | _ _ _ | 2 4 30 | |
| 1 dB Compression | Control Voltage 0/-5 VDC Control Voltage 0/-8 VDC | 0.5 - 3 GHz 0.05 GHz 0.5 - 3 GHz 0.05 GHz | dBm dBm dBm dBm | _ _ _ _ | +27 +21 +33 +26 | _ _ _ _ |
| IP ₂ | For two-tone Input power up to +13 dBm | 0.5 - 3 GHz 0.05 GHz | dBm dBm | _ | +68 +62 | _ |
| IP ₃ | For two-tone Input power up to +13 dBm | 0.5 - 3 GHz 0.05 GHz | dBm dBm | _ | +50 +45 | _ |
| Control Voltages | V _{IN} Low: 0 to –0.2V V _{IN} High: -5V @ 10 μA Typ to –8V | | _ | _ | _ | 5 μΑ 200 μΑ |

^{1.} All specifications apply with 50 ohm impedance connected to all RF ports with 0 and -5 VDC control voltages.

Absolute Maximum Ratings 3,4

| Parameter | Absolute Maximum |
|--|--|
| Input Power 0.05 GHz 0.5 - 3.0 GHz | +27 dBm +34 dBm |
| Control Voltage | -8.5 V <u><</u> Vc <u><</u> +5 V |
| Operating Temperature | -55°C to +125°C |
| Storage Temperature | -65°C to +150°C |

Exceeding any one or combination of these limits may cause permanent damage to this device.

^{2.} Faster switching speed can be achieved with enhanced driver waveform.

M/A-COM does not recommend sustained operation near these survivability limits.

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Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

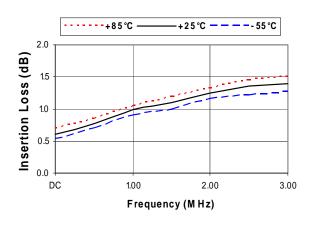
Truth Table (Switch)

| Control Input | | Condition of Switch | | | :h |
|---------------|-----|---------------------|-------------|-------------|-------------|
| Α | В | RF1- RF2 | RF2- RF3 | RF1- RF4 | RF3- RF4 |
| HI | LOW | OFF | ON | ON | OFF |
| LOW | HI | ON | OFF | OFF | ON |

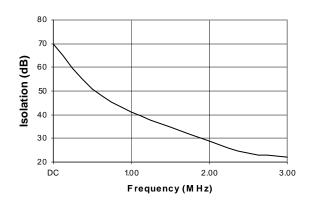
Low = 0.0V, High = -5.0V

Typical Performance Curves

Insertion Loss vs. Frequency

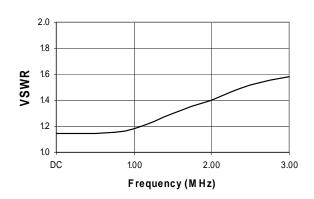


Isolation vs. Frequency



VSWR vs. Frequency

3



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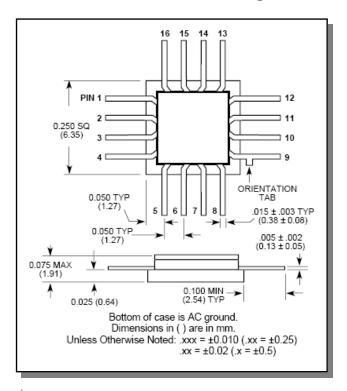
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Lead-Free, CR-4 Ceramic Package[†]



Reference Application Note M538 for lead-free solder reflow recommendations.

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